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# A Low-Power Optical Electron Switch

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## **A low-power optical electron switch**

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#### **Abstract**

An electron beam is deflected when it passes over a silicon-nitride surface, if the surface is illuminated by a lowpower continuous-wave diode laser. A deflection angle of up to 1*.*2 mrad is achieved for an electron beam of 29*μ*rad divergence. A mechanical beam-stop is used to demonstrate that the effect can act as an optical electron switch with a rise and fall time of 6*μ*s. Such a switch provides an alternative means to control electron beams, which may be useful in electron lithography and microscopy.

**Keywords:** electron beams, optical switch, laser beam effects, electron beam lithography

The motion of electron beams is controlled in technologies such as electron lithography, microscopy and diffractometry, in which the use of electric and magnetic fields to focus and steer beams are proven techniques. The control of electron motion with laser fields is also possible with the ponderomotive potential [1, 2]. In principle, such a technique offers the interesting possibility that no electrical components or other hardware needs to be placed in the vicinity of the electron beam. In addition, using the spatial control at optical wavelength scales, electron-optical elements can be realized [3, 4]. However, this optical control requires light intensities of 1014 Wm−2. In this paper we report on an optical electron switch that makes use of a small surface and a low-power laser. Although some material is placed in the vicinity of the electron beam, no electrical feed-throughs are needed. Moreover, the required laser intensity is reduced by ten orders of magnitude as compared to techniques based on the direct interaction between laser light and electrons.

In this paper, it is shown that an electron beam that passes by a surface deflects when the surface is illuminated by a low-power continuous-wave diode laser. While searching for a nano-scale related effect at grazing incidence, a significant and unexpected beam deflection was observed. Deflection angles reached value of up to 1*.*2 mrad. At a distance of 20 cm downstream from the interaction region, this translates to a beam displacement of 240 *μ*m. A beam-stop was placed in the deflected electron beam, so that chopping the laser light results in complete

switching of the electron beam to on and off. A maximum switching rate of  $10^5$  Hz is established. Such an optically controlled electron switch may find applications in electron lithography [5], coherent beam splitting or provide an alternative route to STM-based techniques that probe optically induced near-fields [6, 7].

A schematic of the experimental setup is shown in Figure 1. In our experiment, the electron beam is emitted from a thermionic source with a beam energy of 3*.*98 keV. After passing through two collimation slits of width 5 and 2 *μ*m and separation 24 cm, the beam divergence is reduced to 29*μ*rad. At 6 cm after the second collimation slit, a surface is placed parallel to the beam path. Three different surfaces were tested. The first is a metallic-coated surface with nano-scale grooves. The gold–palladium coating is approximately 1 nm thick and was intended to eliminate charging. Details of the nanofabrication process are given in [8, 9]. The other two are a flat amorphous aluminum (with aluminum oxide on surface) and an uncoated silicon-nitride surface with nanoscale grooves. All three surfaces resulted in electron beam deflection.

Continuous-wave diode lasers with maximum powers of 1 mW, 40 mW, and 5 mW and wavelengths of 532 nm, 685 nm, or 800 nm, respectively, were focused by a cylindrical lens onto the first surface. The other two surfaces were tested with 800 nm light. The height of the laser beam and electron beam were matched by using an edge of the surface structure to block part of these beams. The focal distance is 25 cm, and the focused laser beam waist



**Figure 1.** Setup of the low-power optical electron switch. An electron beam passing close to a surface is deflected by an angle *θ* when the surface is illuminated with a laser beam. The illumination is turned on and off with a mechanical chopper. (For detailed descriptions see text.)

was about 280  $\mu$ m × 1 mm (FWHM). The waist of the light beam was determined by scanning the intensity profile *in situ* with a surface edge. A 10 *μ*m wide electron beam passes at a distance of nominally 20 *μ*m from the vertically mounted metallic surface. Micrometer stages were used to control the horizontal angle (in the *xz*-plane) as well as the vertical and horizontal travel of the surface. Downstream from the metallic surface, the electron beam passes through a parallel plate electrical deflector that aligns the beam with an electrostatic quadrupole lens. This lens magnifies the electron beam image in the horizontal direction by a factor of 65. A chevron multi-channel plate (MCP) detector is placed 26 cm downstream from the surface. A phosphorescent screen follows the MCPs and a camera is used to record the beam profile. Amplifiers and discriminators are used in conjunction with a data acquisition board to record the electron counts as a function of time. Gaussian fits of the beam profiles are used to find the centre positions and the deflection angles.

The vacuum pressure is about 1*.*5 × 10−7 Torr. By chopping the laser, the electron beam image on the MCP detector switches between two positions. The time-averaged image displays two nearly identical electron beam images that are horizontally displaced from each other (Figure 2, top-left inset). An electron beam-stop, depicted in the top-left inset of Figure 2 as a semi-transparent rectangle, is added. The electron counts are recorded as a function of time (Figure 2). The dynamical response of the effect and also the finite electron beam size will limit the rise and fall time. To explore the limit of the response speed, a 40 MHz acousto-optical modulator (AOM) was used (IntraAction Corp. AOM-40N). The amplitude of the acoustic wave was modulated from 1 Hz to 3 MHz. The deflection magnitude for the AOM-modulation was reduced as compared to the mechanical modulation with the chopper, because the laser beam intensity was reduced by about a factor of 2. The inset of Figure 2 shows the scaling of the deflection



Figure 2. Electron counts as a function of time as the laser is switching on and off. Both chopper data (red dots) at 818 Hz and AOM data (black dots) at 1000 Hz are shown. *Top-left inset:* a time-averaged image shows the initial and deflected electron beam. A semi-transparent rectangle is added to depict a movable electron beam-stop. *Topright inset:* the deflection magnitude *θ* is plotted as a function of the chopping frequency *f* . The estimated maximum chopping frequency according our heuristic model,  $f_\text{max}$   $\simeq$  2 MHz, is also drawn (blue line) for comparison. The red dots are data collected with a mechanical chopper and the black dots with an AOM.



**Figure 3.** Distance dependence of the optical electron switch. As the surface is displaced, the distance *x* between the surface and the electron beam is increased (inset). The optical electron switch turns completely on and off up to a distance of 200 *μ*m.

magnitude of the electron beam with the AOM and the chopping frequency. Overall, the deflection magnitude stays constant for frequencies from  $10^2$  to  $3 \times 10^5$  Hz. When the chopping frequencies are below 102 Hz, the deflection magnitude becomes larger. When the AOM frequency increases above  $2 \times 10^5$  Hz, the deflection magnitude decreases to zero.

Electron deflection is measured as a function of distance of the electron beam to the surface. In Figure 3, deflection



**Figure 4.** Beam deflection. *Left:* the measured deflection magnitude is given as a function of *y* (black dots). A measurement of the deflection direction is made at three locations (red circles). The values including sign are indicated (red crosses). Reversals of deflection sign may be explained by our heuristic model (blue line) of light-induced surface-charge redistribution. *Right:* schematics of electron trajectories (black lines) and surface-charge density (color-coded) is shown (see text for model description). Red represents positive charge density. Dark blue represents negative charge density. The red dots indicate the final positions of the electron beams. The interaction between the electron beams and the surface charges is attractive in the middle and repulsive at the sides.

larger than the beam divergence is observed to a distance of up to 200 *μ*m. The Rayleigh length of the focused laser beam is roughly 5 cm for an initial beam width of 1 mm and a the focal length of 25 cm. This is much larger than 200 *μ*m, thus the illumination of the surface is unchanged as the surface is moved with respect to the electron beam. This measurement indicates that the deflection originates from the electron-surface interaction rather than the direct electron-laser interaction. As the interaction range is of the order of 200 *μ*m, the interacting part of the surface is expected to have a length scale of that order of magnitude.

When moving the cylindrical lens in the vertical direction, the laser light crosses the electron beam at different heights. The deflection angle shown in Figure 4 changes its sign as the light crosses through the electron beam. This was determined by placing the beam-stop in such away that the electron beam is half-blocked when the laser is off. If the laser light deflects the beam towards the beam-stop, the electron count rate decreases when the light is on. If the laser light deflect the beam away from the beam-stop, the electron count rate increases when the light is on. The magnitude of the deflection is determined by fitting a double Gaussian to the camera image taken with the beam-stop removed. We observed that as the cylindrical lens is moved vertically and the light approaches the electron beam from one end, the electron beam first is deflected away from the surface, then attracted towards the surface, and back to deflected away again. No significant dependence is observed for surface tilt angles or laser polarizations.

Measurements have also been performed on different material surfaces such an uncoated silicon-nitride membrane (Figure 5) and bulk aluminum. As the vertical position of the laser beam (*y*) is changed, the electron beam deflection reaches a maximum. At *y*-values different from 0, the electron beam is deflected somewhat up and down, likely associated with an induced local charge on the surface. Notice that the deflected electron beam is also tilted in opposite directions for opposite values of *y*. This



**Figure 5.** "Uncoated" deflection measurement. Electron beam deflection is measured as a function of the laser beam position *y*. This measurement is similar to that shown in Figure 4, except the deflection is measured at a location on the surface where the coating was not visible, which we call: "uncoated." The deflection images are shown (left column). For all images the laser beam was chopped on and off, while the electron image was recorded continuously. Note that only deflection in one direction was observed in contrast to that reported in Figure 4 for the coated SiN surface (for a more detailed description see text). An electron microscope image of the SiN surface is shown (top right). A higher magnification image of the edge view of a similar grating (bottom right) is reported earlier [9].

indicates that electrons passing closer to the laser beam are deflected further.

A repulsive deflection of up to 1*.*2 mrad is observed with the silicon-nitride membrane, while at the aluminum surface some small attractive deflection is observed. Given that the deflection effect works with different laser wavelengths at low power, and it can occur at different material surface, we conclude that an optical electron switch based on such a effect is robust.

In the case of an uncoated silicon-nitride surface, the deflection shows only one sign unlike that observed with the nano-structured metallic-coated surface. This suggests that the deflection mechanism could be complex and involve a host of phenomena including laser heating, plasmon or phonon excitation, and surface-charge redistribution. Nevertheless, a simplistic model is constructed to illuminate some features of our experimental data shown in Figure 4. Focused by the cylindrical lens, the laser intensity profile on the metallic-coated surface can be approximated with an elliptical Gaussian,

$$
I(y, z) = I_0 \times \exp\left[-\left(\frac{y}{\Delta y}\right)^2 - \left(\frac{z}{\Delta z}\right)^2\right] \tag{1}
$$

where ∆*y* = 170 *μ*m and ∆*z* = 0*.*6 mm (corresponding to FWHM of 280  $\mu$ m × 1 mm). The maximum intensity is  $I_0 = P_0/(\pi \Delta y \Delta z) = 1.6 \times 10^4$  Wm<sup>-2</sup> and the laser wavelength is  $\lambda$  = 800 nm. The intensity gradient of the laser light can exert a ponderomotive force\* on the electrons in a thin surface layer,

$$
F_{\rm p} = -\frac{e^2 \lambda^2}{8\pi^2 m_{\rm e} c^3 \epsilon_0} \nabla I \tag{2}
$$

If we assume a linear restoring force for the electron,

$$
F_r = -\alpha \, d \tag{3}
$$

where  $\alpha$  is a fitting parameter and  $d$  is the displacement, the induced volume dipole moment can be determined,

$$
P = -n_0 e d = \frac{1}{\alpha} \frac{n_0 e^{3\lambda^2}}{8 \pi^2 m_e c^3 \epsilon_0} \nabla I
$$
 (4)

where  $n_0 = 5.9 \times 10^{28} \text{ m}^{-3}$  is the free electron density of gold [10]. The volume charge distribution  $\rho_{\text{net}}$  is calculated according to  $\rho_{\text{net}} = -\nabla \cdot \mathbf{P}$ . Assuming that the ponderomotive force is effective through a depth of  $\delta_{\text{eff}} = 1 \text{ nm}$  into the metal, the effective surface-charge distribution on the metallic-coated surface can be obtained,

$$
\sigma_{\rm eff} = \rho_{\rm net} \delta_{\rm eff} = -\frac{1}{\alpha} \frac{n_0 e^{3\lambda^2} \delta_{\rm eff}}{8 \pi^2 m_{\rm e} c^3 \epsilon_0} \nabla^2 I \tag{5}
$$

The distance between the free electron beam and the surface is 20 *μ*m, which is much smaller than the length scale of the surface-charge distribution. Thus, close to the surface the free electron beam may experience a electric field approximated by  $E \sigma_{\text{eff}} / 2\epsilon_0(-\hat{x})$ . Assuming that the velocity is constant in the *z*-direction because of the high kinetic energy  $K_0$  = 3.98 keV in the incoming *z*-direction, the deflection angle of the electron beam along the *x*-axis is estimated by

$$
\theta = \frac{\Delta v_x}{v_0} = \frac{e}{4\epsilon_0 K_0} \int_{-\infty}^{+\infty} \sigma_{\text{eff}} \, \text{d}z \tag{6}
$$

After integration, the above equation becomes

$$
\theta = \theta_0 \left[ 1 - 2 \left( \frac{y}{\Delta y} \right)^2 \right] e^{-(y/\Delta y)^2}
$$
 (7)

where

$$
\theta_0 \equiv \frac{\sqrt{\pi} e E_0 \Delta z}{K_0}
$$
  
\n
$$
E_0 \equiv \frac{\sigma_0}{2\epsilon_0}
$$
  
\n
$$
\sigma_0 \equiv \frac{1}{\alpha} \frac{n_0 e^3 \lambda^2 \delta_{\text{eff}} I_0}{8 \pi^2 \epsilon_0 m_e c^3 \Delta y^2}
$$
 (8)

The result of this simplistic model is compared with the experimental data in Figure 4. The fitting parameter is determined to be  $\alpha$  1.52 × 10<sup>-16</sup> Nm<sup>-1</sup>. The linear restoring force (Equation (3)) produces a harmonic motion with fundamental frequency  $\omega_0 = \sqrt{\alpha/m_e}$ . As a damped harmonic oscillator, the frequency response of the electron switch as shown in the inset of Figure 2 is limited to  $f_{\text{max}} = \omega_0 / 2\pi \simeq 2 \text{ MHz}.$ 

Despite some qualitative agreements, this crude model does not explain many details, such as the physical origin of linear restoring force (Equation (3)), the increase of the deflection magnitude at very low frequency (Figure 2), the asymmetric side-peak heights (Figure 4), and the fact that sign reversal of deflection direction is only present on the nanostructured metallic-coated surface but not on the silicon-nitride surface. This heuristic model serves to draw attention to these features of our experimental data.

In summary, when a material surface is placed near an electron beam, a deflection of the electron beam occurs as the surface is illuminated by a low-power laser. Thus, the combination of a material surface, a low-power laser, and a chopping device can make a low-power optical electron switch. Such an optical electron switch may be used for electron beam control in electron lithography and in electron microscopy.

The qualitative agreement between our model and the experimental data may be fortuitous. It suggests that the deflection mechanism is consistent with a surface-charge redistribution that is driven by a mechanism that depends on the intensity gradient of the laser light. But this is only the case for metal coated SiN, and not for uncoated SiN or aluminum.

An implication of this work is that instead of using one laser beam for the optical electron switch, one can use multiple laser beams to form spatial–temporal controlled structures on a material surface. The near field of the surface charge may mimic the pattern of the light, and electron matter waves could be coherently controlled in this manner analogous to the Kapitza–Dirac effect or temporal lensing [11, 12], but without the need for high laser intensity. Finally, we speculate that the combination of laser pulses and nano-fabricated structures will make femtosecond manipulation of free electrons accessible at low intensities [7, 13, 14].

<sup>\*</sup> When a light wave propagates in the solid, the phase relationship between the electric field and the magnetic field is a complex function of the material properties. For a simplistic model, here we assume that the electric field and the magnetic field are in phase.

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